

Patent
Attorney's Docket No. 030681-280

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re P	Patent Application of)			
Sung-nam Lee, et al.		Group Art Unit: 2811			
Application No.: 09/776,846		Examiner: S. Crane			
Filed: February 6, 2001		Confirmation No.: 6862			
For:	NITRIDE SEMICONDUCTOR LIGHT EMITTING DEVICE)))			
		TECH			
	AMENDMENT/REPLY TR	RANSMITTAL LETTER S A			
	ant Commissioner for Patents ngton, D.C. 20231	APR 24 2003 RANSMITTAL LETTER			
Sir:		22			
E	nclosed is a reply for the above-identified pat				
[]	A Petition for Extension of Time is also	enclosed.			
[[] A Terminal Disclaimer and the [] \$55.00 (2814) [] \$110.00 (1814) fee due under 37 C.F.R. § 1.20(d) are also enclosed.				
ζ]	Also enclosed is/are Attachment to Ame	ndment			
[] Small entity status is hereby claimed.				
[[] Applicant(s) request continued examination under 37 C.F.R. § 1.114 and enclose the [] \$375.00 (2801) [] \$750.00 (1801) fee due under 37 C.F.R. § 1.17(e).				
	[] Applicant(s) previously submitted _ requested.	_, on, for which continued examination is			
	Applicant(s) request suspension of action by the Office until at least, which does not exceed three months from the filing of this RCE, in accordance with 37 C.F.R. § 1.103(c). The required fee under 37 C.F.R. § 1.17(i) is enclosed.				
[(1809/2809) is also enclosed.	f Submission under 37 C.F.R. § 1.129(a)			
[]					

Amendment/Reply Transmittal Letter Application No. <u>09/776,846</u> Attorney's Docket No. <u>030681-280</u> Page 2

[] An additional claim fee is required, and is calculated as shown below:

		AMENDED	CLAIM	\mathbf{S}	
	No. OF CLAIMS	HIGHEST NO. OF CLAIMS PREVIOUSLY PAID FOR	EXTRA CLAIMS	RATE	ADDT'L FEE
Total Claims		MINUS =		× \$18.00 (1202) =	-0-
Independent Claims		MINUS =		× \$84.00 (1201) =	-0-
If Amendment adds multiple dependent claims, add \$280.00 (1203)					
Total Amendment Fee				-0-	
If small entity status is claimed, subtract 50% of Total Amendment Fee				-0-	
TOTAL ADDITIONA	L FEE DUE	FOR THIS AMEN	NDMENT		-0-

L	J	A claim lee in	the amount of \$	is enclosed
[]	Charge \$	to Deposit Account N	lo. 02-4800.

The Commissioner is hereby authorized to charge any appropriate fees under 37 C.F.R. §§ 1.16, 1.17, 1.20(d) and 1.21 that may be required by this paper, and to credit any overpayment, to Deposit Account No. 02-4800. This paper is submitted in duplicate.

Respectfully submitted,

BURNS, DOANE, SWECKER & MATHIS, L.L.P.

ву:_

Douglas H. Pearson Registration No. 47,851

P.O. Box 1404 Alexandria, Virginia 22313-1404 (703) 836-6620

Date: April 21, 2003



Patent 128/03
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AMEN	VEU 2003 CENTER	
Assistant Commissioner for Patents		2800

Sir:

In response to the Office Action dated November 20,2002, please amend the aboveidentified application as follows:

IN THE SPECIFICATION:

Washington, D.C. 20231

Please replace the paragraph bridging pages 3 and 4 with the following:

Preferably, the multi-quantum barrier layer is formed by repeatedly depositing a double layer consisting of an $Al_xGa_{1-x}N$ layer and an $In_yGa_{1-y}N$ layer $(0 < x < 1, 0 < y \le 1)$, so that its energy band can have a multi-quantum barrier structure. In this case, the multi-quantum barrier layer is formed by making the thickness of the $Al_xGa_{1-x}N$ layer of each double layer differ from the thicknesses of the $Al_xGa_{1-x}N$ layers of the other double layers

04/29/2003 DSGSF4haRNY1904icO4HROkne9376f4he In_yGa_{1-y}N layer of each double layer differ from the

thicknesses of the In_vGa_{1-v}N layers of the other double layers, thereby making the energy